

NOT RECOMMENDED FOR NEW DESIGN CONTACT US



DMP2070UCB6

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary (Typ. @ VGS = -4.5V, TA = +25°C)

VDSS	RDS(ON)	Qg	Q _{gd}	lp
-20V	55mΩ	2.9nC	0.5nC	-3.5A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Battery managements
- Load switches
- Battery protections

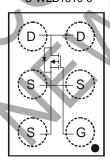
Features and Benefits

- LD-MOS Technology with the Lowest Figure of Merit: $R_{DS(ON)} = 55 m\Omega \text{ to Minimize On-State Losses}$ $Q_g = 2.9 nC \text{ for Ultra-Fast Switching}$
- VGS(TH) = -0.6V Typ. for a Low Turn-On Potential
- CSP with Footprint 1.5mm × 1.0mm
- Height = 0.62mm for Low Profile
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at
 - https://www.diodes.com/products/automotive/automotive-products/.
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
 https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: U-WLB1510-6
- Terminal Connections: See Diagram Below
- Weight: 0.0018 grams (Approximate)





Top View

Ordering Information (Note 4)

Part Number	Paskaga	Packing			
Part Number	Package	Qty.	Carrier		
DMP2070UCB6-7	U-WLB1510-6	3,000	Tape & Reel		

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3).compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- $4. For packaging details, go to our website at \ https://www.diodes.com/design/support/packaging/diodes-packaging/. \\$



Marking Information

U-WLB1510-6



2W = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022)M = Month (ex: 9 = September)

Date Code Key

Year	2011		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	Υ		J	K	L	М	N	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic			-	Symbol	Value	Units
Drain-Source Voltage				V _{DSS}	-20	V
Gate-Source Voltage			7	Vgss	±8	V
Continuous Drain Current (Note 5) V _{GS} = -4.5V	Steady State	$T_A = +25$ °C $T_A = +70$ °C		lp	-2.5 -2.0	А
Continuous Drain Current (Note 6) V _{GS} = -4.5V	Steady State	$T_A = +25$ °C $T_A = +70$ °C		lo	-3.5 -2.8	А
Pulsed Drain Current (Note 7)			,	Ірм	-12	Α
Maximum Continuous Body Diode Forward Current	(Note 6)			Is	-1.8	А

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	0.92	W
Total Power Dissipation (Note 6)	PD	1.47	W
Thermal Resistance, Junction to Ambient (Note 5)	RеJA	136	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	RеJA	84	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Notes:

^{5.} Device mounted on FR-4 PCB with minimum recommended pad layout.

^{6.} Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu. 7. 300ms pulse, pulse duty cycle ≤ 2%.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

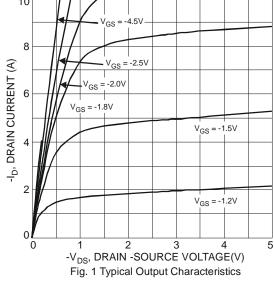
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)				•	•		
Drain-Source Breakdown Voltage		BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$
Zero Gate Voltage Drain Current	@T _C = +25°C	IDSS	_	_	-1	μΑ	V _{DS} = -16V, V _{GS} = 0V
Gate-Source Leakage		I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 8V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage		V _{GS(TH)}	-0.4	-0.6	-1.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
				55	70		Vgs = -4.5V, ID = -1A
Static Drain-Source On-Resistance			_	70	90	mΩ	$V_{GS} = -2.5V$, $I_{D} = -1A$
Static Drain-Source On-Resistance		RDS(ON)		90	110		$V_{GS} = -1.8V, I_{D} = -1A$
				110	150		Vgs = -1.5V, ID = -1A
Forward Transfer Admittance		Y _{fs}	_	12	_	S	V _{DS} = -10V, I _D = -1A
Diode Forward Voltage (Note 6)	VsD	_	-0.7	-1	V	Vgs = 0V, Is = -1A	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Input Capacitance			210	J	pF	V (2)/ V (2)/
Output Capacitance		Coss	_	92		pF	V _{DS} = -10V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance		C _{rss}	_	38	-	pF	1 = 1.0W112
Series Gate Resistance		Rg	-	5.3	1	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge		Qg	_	2.9	_	nC	15/1/1/ 10//
Gate-Source Charge		Qgs		0.3	_	nC	$V_{GS} = -4.5V$, $V_{DS} = -10V$
Gate-Drain Charge		Qgd	7-4	0.5	_	nC	I _D = -1A
Turn-On Delay Time		t _{D(ON)}	13	7.3		ns	
Turn-On Rise Time		tR	1-1	14.0		ns	V _{DD} = -10V, V _{GS} = -4.5V
Turn-Off Delay Time		tD(OFF)	4	42.6		ns	$I_{DS} = -1A$, $R_G = 20\Omega$
Turn-Off Fall Time		tF	\	32	→	ns	1

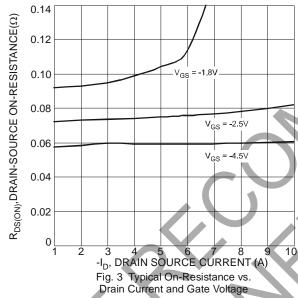
Notes:

- 8. Short duration pulse test used to minimize self-heating effect.9. Guaranteed by design. Not subject to production testing.









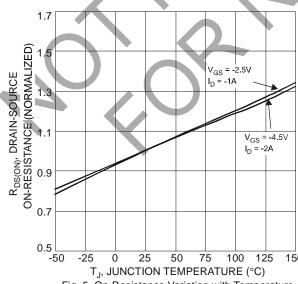
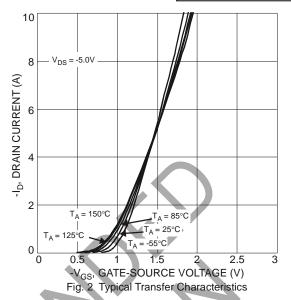
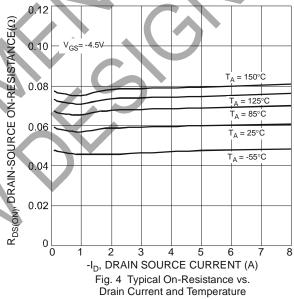
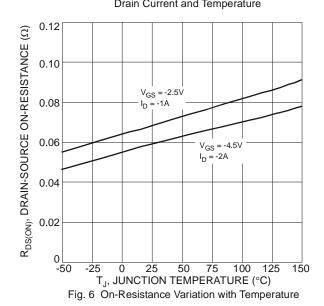


Fig. 5 On-Resistance Variation with Temperature











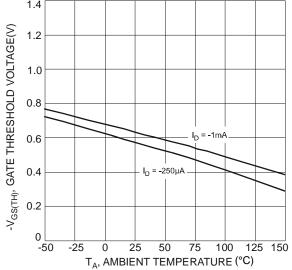
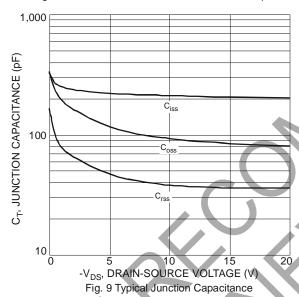
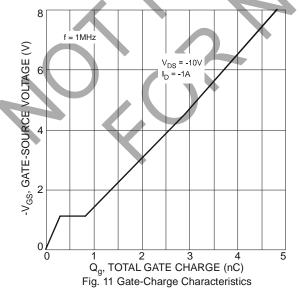
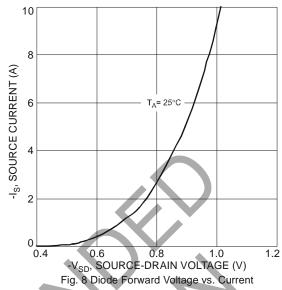


Fig. 7 Gate Threshold Variation vs. Ambient Temperature







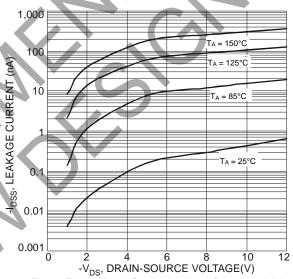
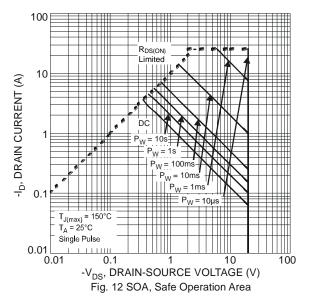
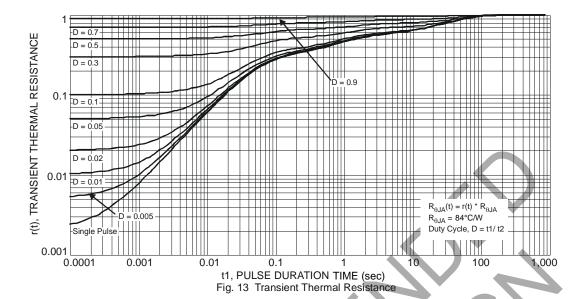


Fig. 10 Typical Drain-Source Leakage Current vs. Voltage





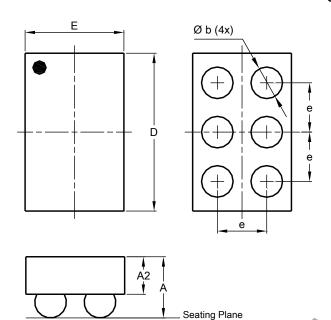




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-WLB1510-6

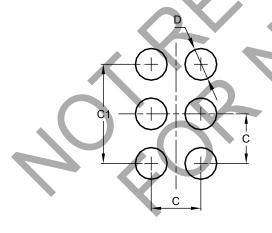


U-WLB1510-6							
Dim	Min	Max	Тур				
Α	1	0.62					
A2			0.038				
b	0.27	0.37	0.32				
D	1.40	1.50	1.50				
E	0.90	1.00	1.00				
е			0.50				
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-WLB1510-6



Dimensions	Value (in mm)				
С	0.50				
C1	1.00				
ח	0.25				



IMPORTANT NOTICE

- 1. DIODES INCORPORATED AND ITS SUBSIDIARIES ("DIODES") MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
- 2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes products. Diodes products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of the Diodes products for their intended applications, (c) ensuring their applications, which incorporate Diodes products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
- 3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.
- 4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
- 5. Diodes products are provided subject to Diodes Standard Terms and Conditions of Sale (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
- 6. Diodes products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
- 7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
- 8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use

Copyright © 2022 Diodes Incorporated

www.diodes.com